



PNP BDX34 – BDX34A – BDX34B – BDX34C

COMPLEMENTARY SILICON POWER DARLINGTON TRANSISTORS

The BDX34B, BDX34B and BDX34C are silicon epitaxial-base PNP power transistors in monolithic Darlington configuration and are mounted in Jedec TO-220 plastic package. They are intended for use in power linear and switching applications. The complementary NPN types are the BDX33A, BDX33B and BDX33C respectively. Compliance to RoHS.

ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings		Value	Unit	
V_{CE0}	Collector-Emitter Voltage	$I_B=0$	BDX34	-45	V
			BDX34A	-60	
			BDX34B	-80	
			BDX34C	-100	
V_{CBO}	Collector-Base Voltage	$I_E=0$	BDX34	-45	V
			BDX34A	-60	
			BDX34B	-80	
			BDX34C	-100	
I_C	Collector Current	$I_{C(RMS)}$	-10	A	
		I_{CM}	-15		
I_B	Base Current		-0.25	A	
P_T	Power Dissipation	@ $T_C = 25^\circ$	70	W	
T_J	Junction Temperature		-65 to +150	$^\circ C$	
T_S	Storage Temperature				

THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R_{thJ-C}	Thermal Resistance, Junction to Case	1.78	$^\circ C/W$



PNP BDX34 – BDX34A – BDX34B – BDX34C

ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)	Min	Typ	Max	Unit		
$V_{CE0(SUS)}$	Collector-Emitter Breakdown Voltage (*)	$I_C = -100 \text{ mA}$	BDX34	-45	-	-	V	
			BDX34A	-60	-	-		
			BDX34B	-80	-	-		
			BDX34C	-100	-	-		
$V_{CER(SUS)}$	Collector-Emitter Sustaining Voltage (*)	$I_B = -100 \text{ mA}$ $R_{BE} = 100\Omega$	BDX34	-45	-	-	V	
			BDX34A	-60	-	-		
			BDX34B	-80	-	-		
			BDX34C	-100	-	-		
$V_{CEV(SUS)}$	Collector-Emitter Sustaining Voltage (*)	$I_C = 1-00 \text{ mA}$ $V_{BE} = -1.5 \text{ V}$	BDX34	-45	-	-	V	
			BDX34A	-60	-	-		
			BDX34B	-80	-	-		
			BDX34C	-100	-	-		
I_{CEO}	Collector Cutoff Current		$V_{CB} = -22\text{V}$	BDX34	-	-	-0.5	mA
			$V_{CB} = -30\text{V}$	BDX34A	-	-		
			$V_{CB} = -40\text{V}$	BDX34B	-	-		
			$V_{CB} = -50\text{V}$	BDX34C	-	-		
			$V_{CB} = -22\text{V}, T_C = 100^\circ\text{C}$	BDX34	-	-	-10	
			$V_{CB} = -30\text{V}, T_C = 100^\circ\text{C}$	BDX34A	-	-		
			$V_{CB} = -40\text{V}, T_C = 100^\circ\text{C}$	BDX34B	-	-		
			$V_{CB} = -50\text{V}, T_C = 100^\circ\text{C}$	BDX34C	-	-		
I_{EBO}	Emitter Cutoff Current	$V_{BE} = -5 \text{ V}$	BDX34	-	-	-5.0	mA	
			BDX34A					
			BDX34B					
			BDX34C					
			BDX34					
			BDX34A					
			BDX34B					
			BDX34C					
I_{CBO}	Collector-Base Cutoff Current		$V_{CBO} = -45 \text{ V}$	BDX34	-	-	-0.2	mA
			$V_{CBO} = -60 \text{ V}$	BDX34A	-	-		
			$V_{CBO} = -80 \text{ V}$	BDX34B	-	-		
			$V_{CBO} = -100 \text{ V}$	BDX34C	-	-		



PNP BDX34 – BDX34A – BDX34B – BDX34C

ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)		Min	Typ	Max	Unit
I_{CBO}	Collector-Base Cutoff Current	$V_{CBO}=-45\text{ V}$ $T_C=100^\circ\text{C}$	BDX34	-	-	-5	mA
		$V_{CBO}=-60\text{ V}$ $T_C=100^\circ\text{C}$	BDX34A	-	-		
		$V_{CBO}=-80\text{ V}$ $T_C=100^\circ\text{C}$	BDX34B	-	-		
		$V_{CBO}=-100\text{ V}$ $T_C=100^\circ\text{C}$	BDX34C	-	-		
$V_{CE(SAT)}$	Collector-Emitter saturation Voltage (*)	$I_C=-4.0\text{ A}, I_B=-8.0\text{ mA}$	BDX34	-	-	-2.5	V
			BDX34A				
			BDX34B				
			BDX34C				
		$I_C=-3.0\text{ A}, I_B=-6.0\text{ mA}$	BDX34	-	-	-2.5	
			BDX34A				
			BDX34B				
			BDX34C				
V_F	Forward Voltage (pulse method)	$I_F=-8\text{ A}$	BDX34	-	-	4.0	V
			BDX34A				
			BDX34B				
			BDX34C				
V_{BE}	Base-Emitter Voltage (*)	$I_C=-4.0\text{ A}, V_{CE}=-3.0\text{ V}$	BDX34	-	-	-2.5	V
			BDX34A				
		$I_C=-3.0\text{ A}, V_{CE}=-3.0\text{ V}$	BDX34B	-	-	-2.5	
			BDX34C				
h_{FE}	DC Current Gain (*)	$V_{CE}=-3.0\text{ V}, I_C=-4.0\text{ A}$	BDX34	750	-	-	-
			BDX34A				
		$V_{CE}=-3.0\text{ V}, I_C=-3.0\text{ A}$	BDX34B	750	-	-	
			BDX34C				

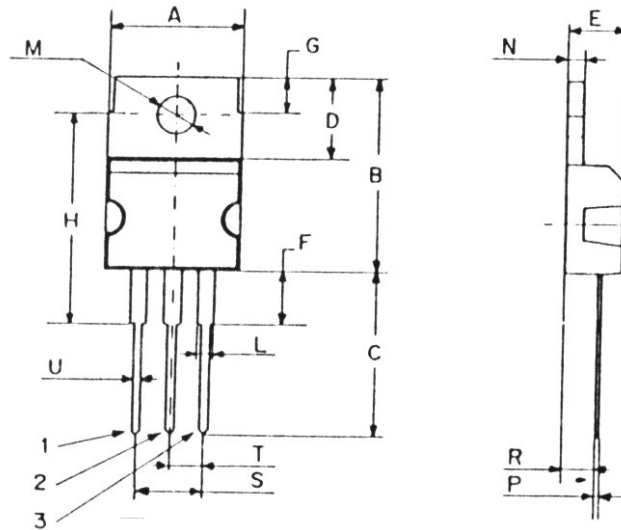
(*) Pulse Width $\approx 300\ \mu\text{s}$, Duty Cycle $\angle 2.0\%$



PNP BDX34 – BDX34A – BDX34B – BDX34C

MECHANICAL DATA CASE TO-220

DIMENSIONS (mm)		
	Min.	Max.
A	9,90	10,30
B	15,65	15,90
C	13,20	13,40
D	6,45	6,65
E	4,30	4,50
F	2,70	3,15
G	2,60	3,00
H	15,75	17,15
L	1,15	1,40
M	3,50	3,70
N	-	1,37
P	0,46	0,55
R	2,50	2,70
S	4,98	5,08
T	2,49	2,54
U	0,70	0,90



Pin 1 :	Base
Pin 2 :	Collector
Pin 3 :	Emitter
Case :	Collector

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